FPGA-based Readout for **Double-Sided Silicon Strip Detectors**

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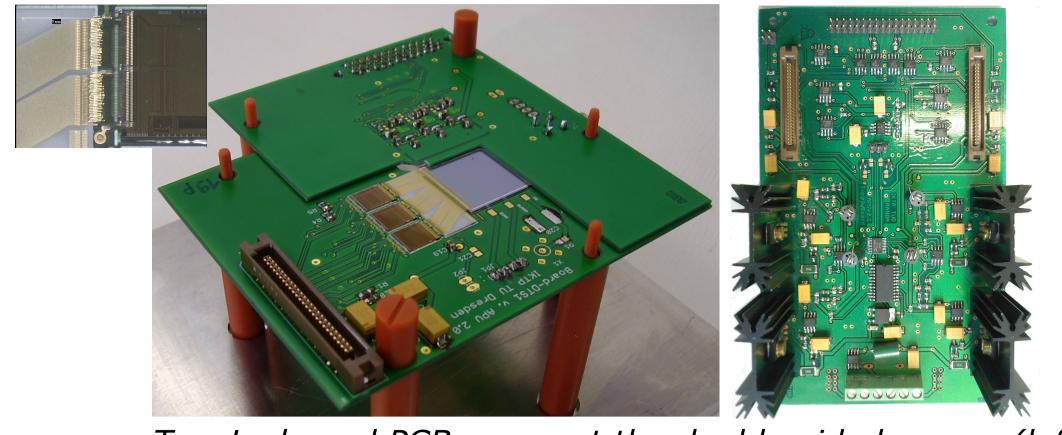
Supported by BMBF

Motivation

- Initial situation
- software data processing based upon PCI-ADC card → very inefficient, low readout rate
- Objective

2048

- implement first level readout structures in FPGA
 - → obtain effective data reduction, low latency, short deadtime

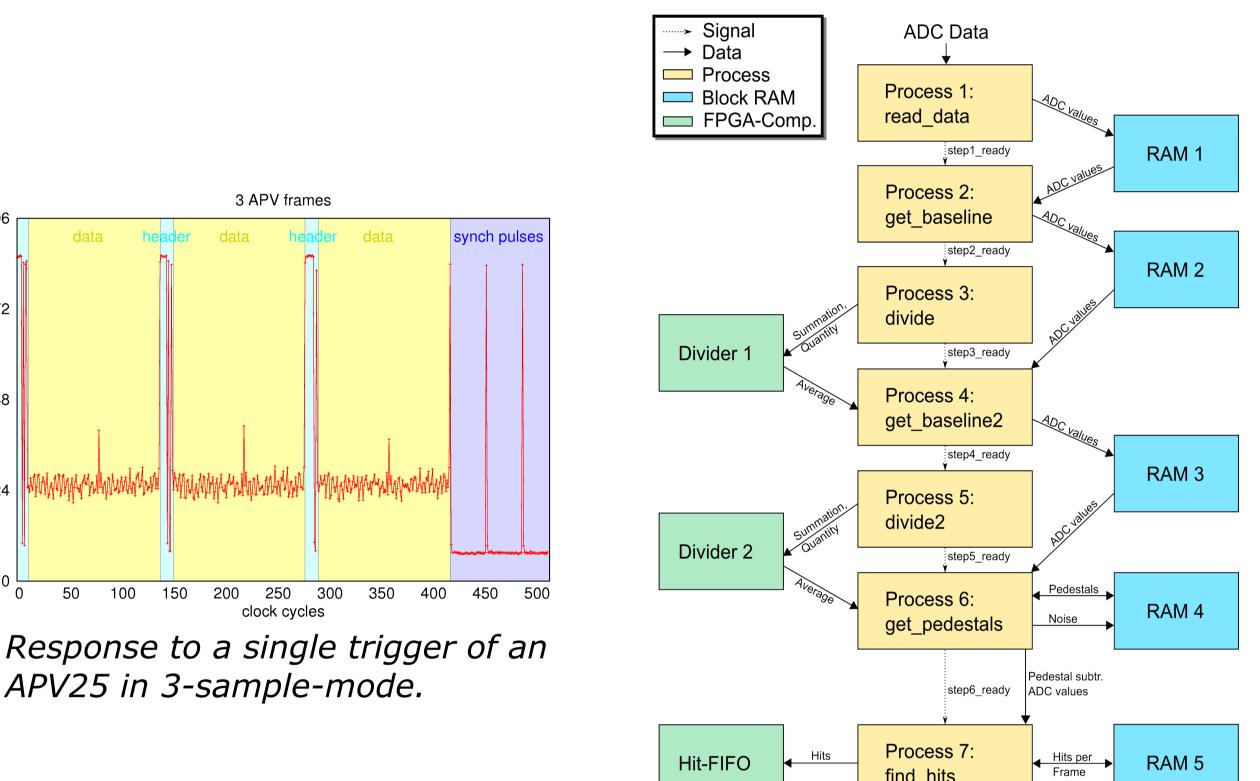


Two L-shaped PCBs support the double-sided sensor (left). Board to supply voltages to the sensor board (right).





FPGA based VME module with mezzanine expansion slots (left) and sampling ADC mezzanine card (right).



Scheme of the data processing implemented for every frontend.

Hardware

Test setup

L-shaped PCB boards on both sensor sides support:

frontend chip: APV25-S1

TELESCOPE [ITC] (2x2 cm²; 50 μm pitch) sensor:

RHe Microsystems Radeberg RHe assembly:

DAQ hardware

- FPGA based VME module (Spartan-3, 3x 80pin mezzanine slots)
- sampling ADC mezzanine card (4 channel, 12 bit, 65 MSPS)

FPGA Processes

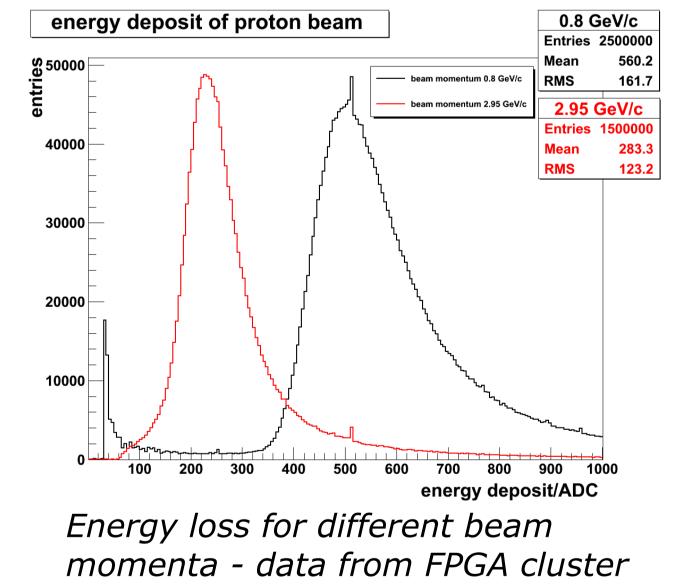
- Pipelined data processing consists of
- separation of data and header
- two step baseline determination
- pedestal calculation
- hitfinder
- clusterfinder
- Parameters adjustable via VMEbus
- frontend I²C-register settings
- trigger pattern
- phase shift between frontend clock and sampling clock
- hitfinder criteria

Results

- demonstrated powerful readout system
- realtime data processing

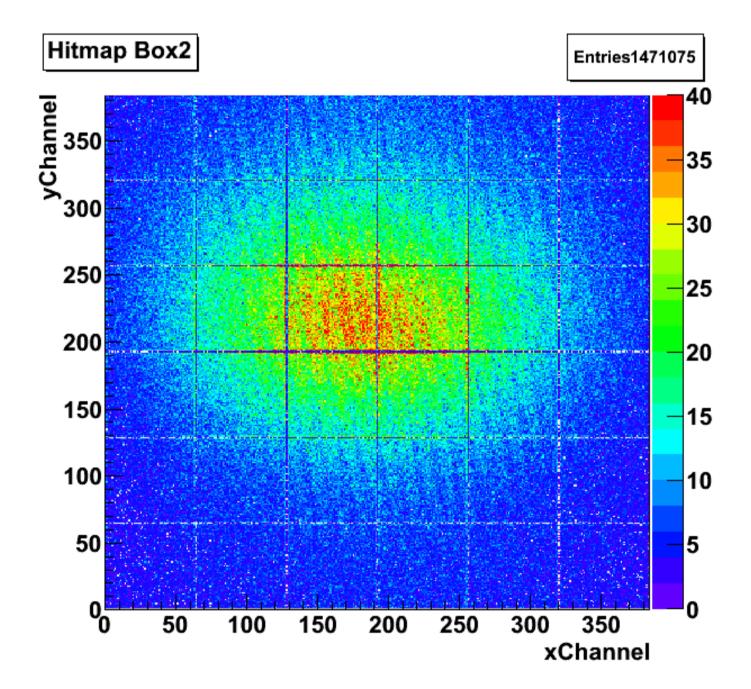
APV25 in 3-sample-mode.

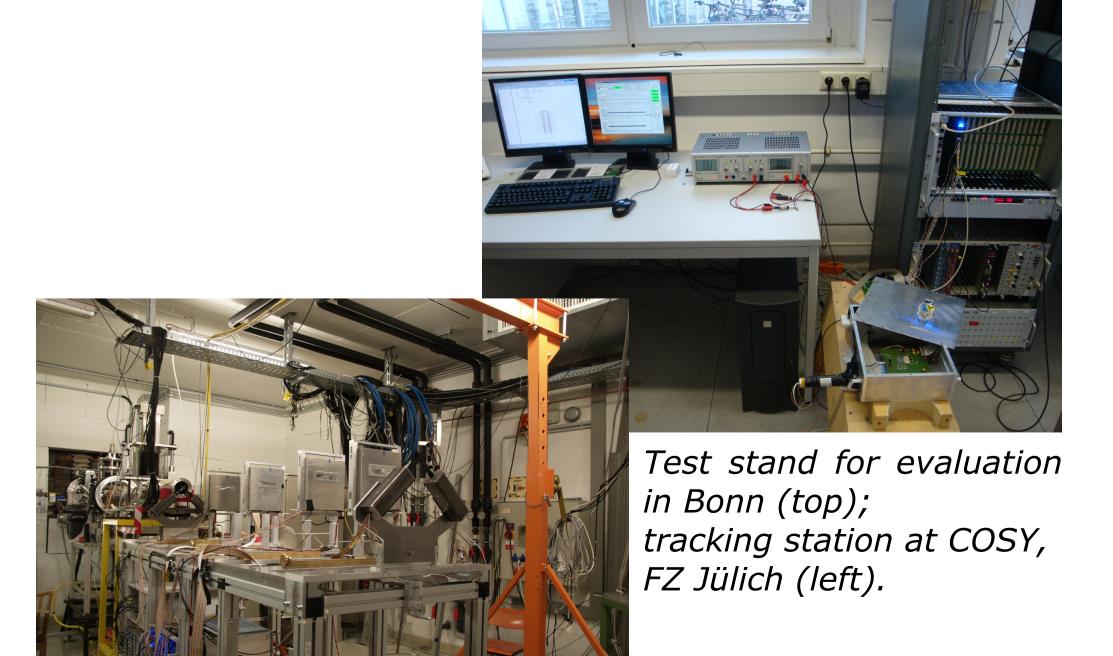
- significant low latency data reduction by a factor of 1:100
- readout rates up to 30 kHz achievable
- no deadtime caused by readout → limited by APV25-S1
- reliability validated in various measurements



Hit pattern on sensor caused by a

converted photon beam (right).



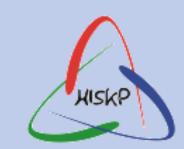


Applications

- measurements with a tracking station
 - COSY, FZ Jülich proton beam up to 3 GeV/c
 - DESY, Hamburg electron beam up to 5 GeV
 - ELSA, Bonn - electron and photon beams up to 3 GeV
- stand-alone test stations
- prototyping

finder (top).

- detector tests
- adaptation to various detector types, e.g. GEM



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